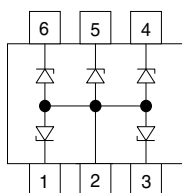
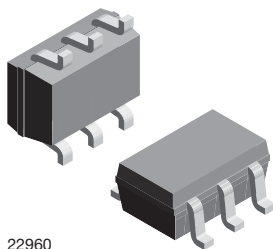


Five-Line ESD Protection Diode Array in SOT-363

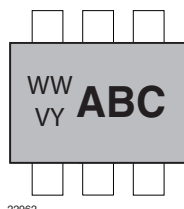


22961



22960

MARKING (example only)



22962

Bar = cathode marking

X = date code

Y = type code (see table below)

DESIGN SUPPORT TOOLS AVAILABLE


[3D Models](#)

FEATURES

- Compact SOT-363 package
- 5-line unidirectional ESD-protection
- Working range 5V to 26 V
- ESD immunity acc. IEC 61000-4-2
±20kV to ± 30 kV contact discharge
±20kV to ± 30 kV air discharge
- AEC-Q101 qualified available
- Lead plating: Sn (e3)
 - soldering can be checked by standard vision inspection
 - (AOI = automated optical inspection)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE
GREEN
(5-2008)

ORDERING INFORMATION					
PART NUMBER (EXAMPLE)	AEC-Q101 QUALIFIED	ENVIRONMENTAL AND QUALITY CODE			ORDERING CODE (EXAMPLE)
		RoHS COMPLIANT + LEAD (Pb)-FREE TERMINATIONS	TIN PLATED	3K PER 7" REEL (8 mm TAPE)	
		GREEN		MOQ = 15K/BOX	
VESD05A5-06G	-	G	3	-08	VESD05A5-06G-G3-08
VESD05A5-06G	H	G	3	-08	VESD05A5-06GHG3-08

PACKAGE DATA						
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS
VESD05A5-06G	SOT-363	D05	7.22 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260°C
VESD12A5-06G		D12				
VESD16A5-06G		D16				
VESD26A5-06G		D26				

**ABSOLUTE MAXIMUM RATINGS VESD05A5-06G**

PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	Acc. IEC 61000-4-5, 8/20 μ s/single shot	I _{PPM}	8.7	A
Peak pulse power	Acc. IEC 61000-4-5, 8/20 μ s/single shot	P _{PP}	100	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	30	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses		30	kV
Operating temperature	Junction temperature	T _J	-55 to +150	°C
Storage temperature		T _{stg}	-55 to +150	°C

ABSOLUTE MAXIMUM RATINGS VESD12A5-06G

PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	Acc. IEC 61000-4-5, 8/20 μ s/single shot	I _{PPM}	4.4	A
Peak pulse power	Acc. IEC 61000-4-5, 8/20 μ s/single shot	P _{PP}	100	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	30	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses		30	kV
Operating temperature	Junction temperature	T _J	-55 to +150	°C
Storage temperature		T _{stg}	-55 to +150	°C

ABSOLUTE MAXIMUM RATINGS VESD16A5-06G

PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	Acc. IEC 61000-4-5, 8/20 μ s/single shot	I _{PPM}	3.6	A
Peak pulse power	Acc. IEC 61000-4-5, 8/20 μ s/single shot	P _{PP}	100	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	30	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses		30	kV
Operating temperature	Junction temperature	T _J	-55 to +150	°C
Storage temperature		T _{stg}	-55 to +150	°C

ABSOLUTE MAXIMUM RATINGS VESD26A5-06G

PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT
Peak pulse current	Acc. IEC 61000-4-5, 8/20 μ s/single shot	I _{PPM}	2.1	A
Peak pulse power	Acc. IEC 61000-4-5, 8/20 μ s/single shot	P _{PP}	100	W
ESD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	V _{ESD}	20	kV
	Air discharge acc. IEC 61000-4-2; 10 pulses		20	kV
Operating temperature	Junction temperature	T _J	-55 to +150	°C
Storage temperature		T _{stg}	-55 to +150	°C

**ELECTRICAL CHARACTERISTICS VESD05A5-06G**(T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines
Reverse stand off voltage	Max. reverse working voltage	V _{RWM}	-	-	5	V
Reverse voltage	at I _R = 1 µA	V _R	5	-	-	V
Reverse current	at V _R = 5 V	I _R	-	0.01	0.1	µA
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	6.85	7.26	7.65	V
Reverse clamping voltage	at I _{PP} = I _{PPM} = 8.7 A, t _p = 8/20 µs	V _C	-	10.3	11.5	V
Forward clamping voltage	at I _{PP} = 1 A, t _p = 300 µs	V _F	0.9	1.1	1.2	V
	at I _{PP} = I _{PPM} = 8.7 A, t _p = 8/20 µs	V _F	-	2.2	2.74	V
Dynamic resistance	t _p = 100 ns (TLP; pin 2-1)	r _{dyn}	-	0.2	-	Ω
Capacitance	at V _R = 0 V; f = 1 MHz	C _D	53	67	81	pF

ELECTRICAL CHARACTERISTICS VESD12A5-06G(T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines
Reverse stand off voltage	Max. reverse working voltage	V _{RWM}	-	-	12	V
Reverse voltage	at I _R = 0.1 µA	V _R	12	-	-	V
Reverse current	at V _R = 12 V	I _R	-	0.01	0.1	µA
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	13.9	14.7	15.5	V
Reverse clamping voltage	at I _{PP} = I _{PPM} = 4.4 A, t _p = 8/20 µs	V _C	-	20.5	22.7	V
Forward clamping voltage	at I _{PP} = 1 A, t _p = 300 µs	V _F	0.9	1.1	1.2	V
	at I _{PP} = I _{PPM} = 4.4 A, t _p = 8/20 µs	V _F	-	1.6	1.88	V
Dynamic resistance	t _p = 100 ns (TLP); pin 2-1	r _{dyn}	-	0.4	-	Ω
Capacitance	at V _R = 0 V; f = 1 MHz	C _D	26	33	40	pF

ELECTRICAL CHARACTERISTICS VESD16A5-06G(T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines
Reverse stand off voltage	Max. reverse working voltage	V _{RWM}	-	-	16	V
Reverse voltage	at I _R = 0.1 µA	V _R	16	-	-	V
Reverse current	at V _R = 16 V	I _R	-	0.01	0.1	µA
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	17	17.9	18.8	V
Reverse clamping voltage	at I _{PP} = I _{PPM} = 3.6 A, t _p = 8/20 µs	V _C	-	25.3	28	V
Forward clamping voltage	at I _{PP} = 1 A, t _p = 300 µs	V _F	0.9	1.1	1.2	V
	at I _{PP} = I _{PPM} = 3.6 A, t _p = 8/20 µs	V _F	-	1.5	1.72	V
Dynamic resistance	t _p = 100 ns (TLP); pin 2-1	r _{dyn}	-	0.53	-	Ω
Capacitance	at V _R = 0 V; f = 1 MHz	C _D	21	27	33	pF

**ELECTRICAL CHARACTERISTICS VESD26A5-06G**(T_{amb} = 25 °C, unless otherwise specified)

PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT
Protection paths	Number of lines which can be protected	N _{channel}	-	-	1	lines
Reverse stand off voltage	Max. reverse working voltage	V _{RWM}	-	-	26	V
Reverse voltage	at I _R = 0.1 μA	V _R	26	-	-	V
Reverse current	at V _R = 26 V	I _R	-	< 0.01	0.1	μA
Reverse breakdown voltage	at I _R = 1 mA	V _{BR}	27.6	29.1	30.6	V
Reverse clamping voltage	at I _{PP} = I _{PPM} = 2.1 A, t _p = 8/20 μs	V _C	-	43	48	V
Forward clamping voltage	at I _{PP} = 1 A, t _p = 300 μs	V _F	0.9	1.1	1.2	V
	at I _{PP} = I _{PPM} = 2.1 A, t _p = 8/20 μs	V _F	-	1.3	1.42	V
Dynamic resistance	t _p = 100 ns (TLP); pin 2-1	r _{dyn}	-	1.9	-	Ω
Capacitance	at V _R = 0 V; f = 1 MHz	C _D	14	17.5	21	pF

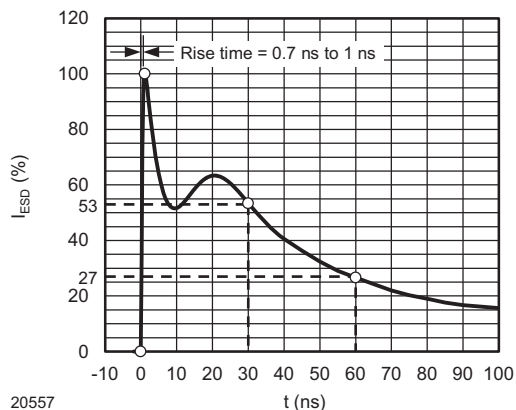


Fig. 1 - ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330 Ω / 150 pF)

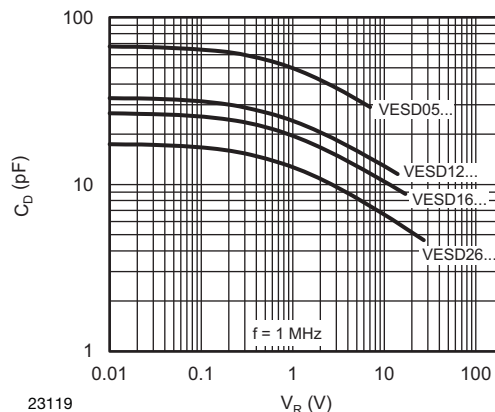


Fig. 4 - Typical Capacitance vs. Reverse Voltage

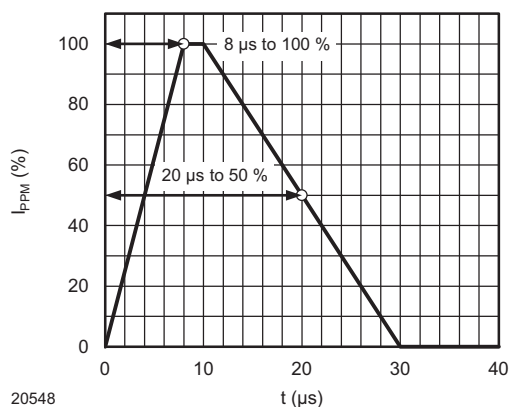


Fig. 2 - 8/20 μ s Peak Pulse Current Wave Form acc. IEC 61000-4-5

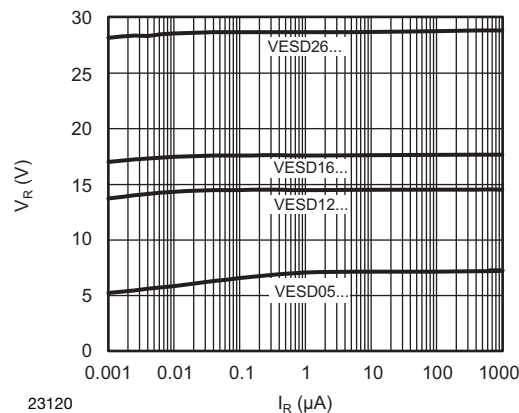


Fig. 5 - Typical Reverse Voltage vs. Reverse Current

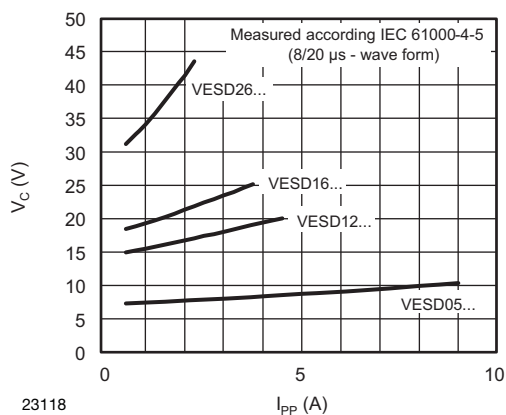


Fig. 3 - Typical Peak Clamping Voltage vs. Peak Pulse Current

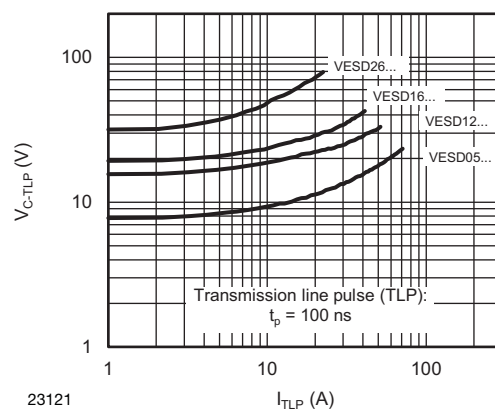
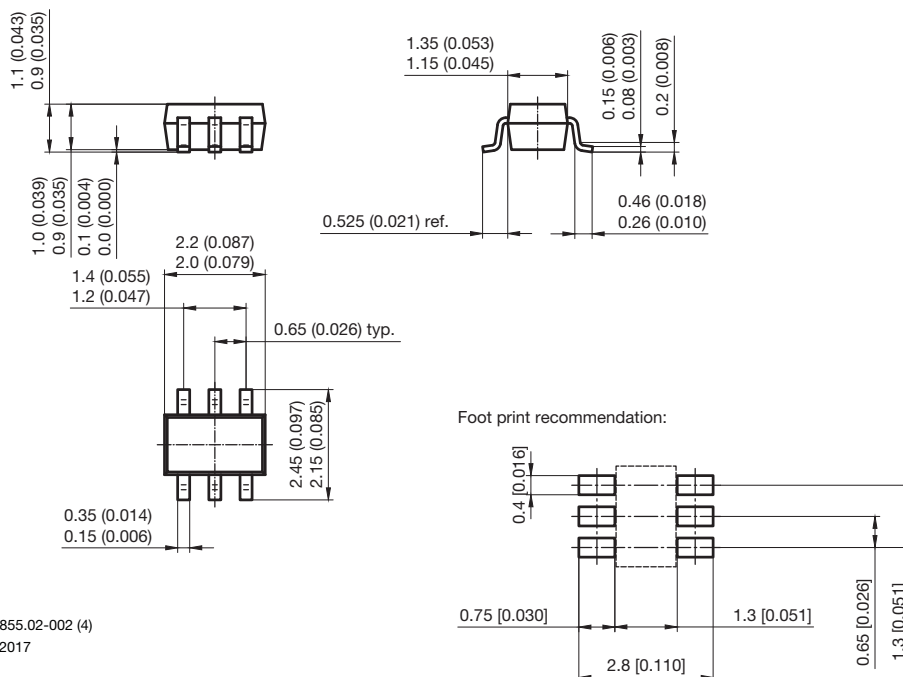


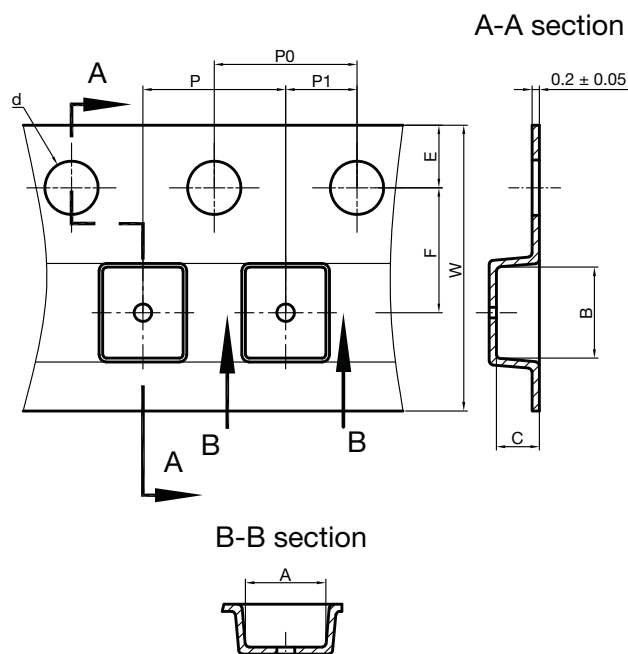
Fig. 6 - Typical Clamping Voltage vs. Peak Pulse Current

PACKAGE DIMENSIONS in millimeters (Inches): SOT-363



Document no.: S8-V-3855.02-002 (4)
Rev.1 - Date: 23. Jun. 2017
23122

CARRIER TAPE SOT-363



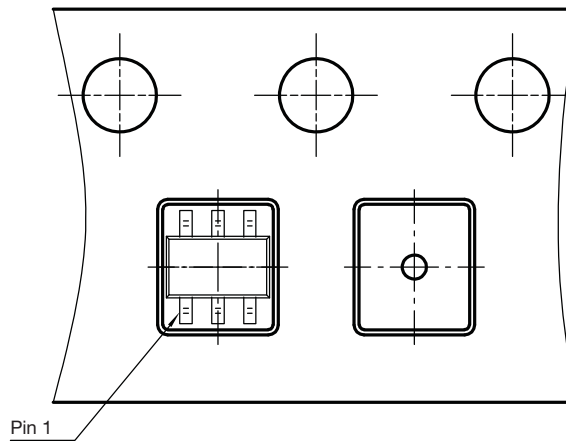
Cummulative tolerances of 10 sprocket holes is ± 0.2 mm

Dimensions in millimeters										
Packaging type	A	B	C	d	E	F	P0	P	P1	W
SOT-363	2.25	2.55	1.20	Ø 1.5	1.75	3.50	4.00	4.00	2.00	8.00
(Tolerance)	± 0.1	± 0.1	± 0.1	+0.1/-0	± 0.1	± 0.1	± 0.05	± 0.1	± 0.05	+0.3/-0.1

Document no. S8-V-3855.02-003 (4)
Created - Date: 25. April. 2017
22968



ORIENTATION IN CARRIER TAPE SOT-363



Document no. S8-V-3855.02-004 (4)
Created - Date: 25. April 2017



Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

Данный компонент на территории Российской Федерации

Вы можете приобрести в компании MosChip.

Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

Офис по работе с юридическими лицами:

105318, г.Москва, ул.Щербаковская д.3, офис 1107, 1118, ДЦ «Щербаковский»

Телефон: +7 495 668-12-70 (многоканальный)

Факс: +7 495 668-12-70 (доб.304)

E-mail: info@moschip.ru

Skype отдела продаж:

moschip.ru

moschip.ru_4

moschip.ru_6

moschip.ru_9